

Quad 2-Input AND Gate

MM74HC08

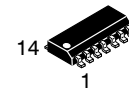
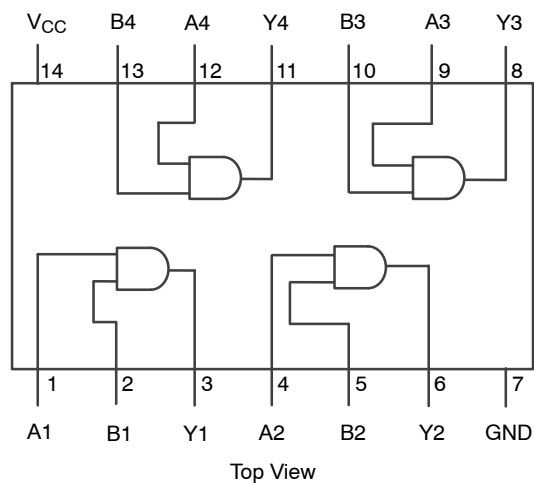
General Description

The MM74HC08 AND gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. The HC08 has buffered outputs, providing high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

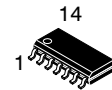
Features

- Typical Propagation Delay: 12 ns (t_{PHL}), 7 ns (t_{PLH})
- Fan-out of 10 LS-TTL Loads
- Quiescent Power Consumption: 2 μ A Maximum at Room Temperature
- Low Input Current: 1 μ A Maximum
- This Device is Pb-Free and Halide Free

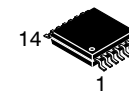
Connection Diagram



SOIC-14 NB
CASE 751A

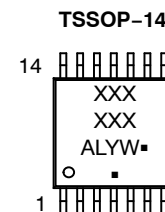
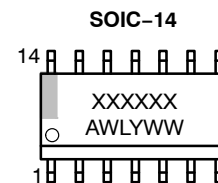


SOIC14
CASE 751EF



TSSOP-14 WB
CASE 948G

MARKING DIAGRAMS



XXXXXX = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot Number
Y = Year
WW, YW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

MM74HC08

ABSOLUTE MAXIMUM RATINGS (Note 1)

Symbol	Rating	Min	Max	Unit
V_{CC}	Supply Voltage	-0.5	+6.5	V
V_{IN}	DC Input Voltage	-0.5	$V_{CC} + 0.5$	V
V_{OUT}	DC Output Voltage	-0.5	$V_{CC} + 0.5$	V
I_{IK}, I_{OK}	Clamp Diode Current		± 20	mA
I_{OUT}	DC Output Current, per pin		± 25	mA
I_{CC}	DC V_{CC} or GND Current, per pin		± 50	mA
T_{STG}	Storage Temperature Range	-65	+150	°C
P_D	Power Dissipation		1077 833	mW
				SOIC TSSOP
T_L	Lead Temperature (Soldering 10 second)		260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Unless otherwise specified all voltages are referenced to ground.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	Supply Voltage	2	6	V
V_{IN}, V_{OUT}	DC Input or Output Voltage	0	V_{CC}	V
T_A	Operating Temperature Range	-55	+125	°C
t_r, t_f	Input Rise or Fall Times	$V_{CC} = 2.0\text{ V}$	1000	ns
		$V_{CC} = 4.5\text{ V}$	500	ns
		$V_{CC} = 6.0\text{ V}$	400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

MM74HC08

DC ELECTRICAL CHARACTERISTICS (Note 2)

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = 25°C		T _A = -40°C to 85°C	T _A = -55°C to 125°C	Unit
				Typ	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage	2.0			1.5	1.5	1.5	V
		4.5			3.15	3.15	3.15	
		6.0			4.2	4.2	4.2	
V _{IL}	Maximum LOW Level Input Voltage	2.0			0.5	0.5	0.5	V
		4.5			1.35	1.35	1.35	
		6.0			1.8	1.8	1.8	
V _{OH}	Minimum HIGH Level Output Voltage	2.0	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤20 μA	2.0	1.9	1.9	1.9	V
		4.5		4.5	4.4	4.4	4.4	
		6.0		6.0	5.9	5.9	5.9	
		4.5	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤4.0 mA	4.2	3.98	3.84	3.7	
		6.0	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤5.2 mA	5.7	5.48	5.34	5.2	
V _{OL}	Maximum LOW Level Output Voltage	2.0	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤20 μA	0	0.1	0.1	0.1	V
		4.5		0	0.1	0.1	0.1	
		6.0		0	0.1	0.1	0.1	
		4.5	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤4.0 mA	0.2	0.26	0.33	0.4	
		6.0	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤5.2 mA	0.2	0.26	0.33	0.4	
I _{IN}	Maximum Input Current	6.0	V _{IN} = V _{CC} or GND		±0.1	±1.0	±1.0	μA
I _{CC}	Maximum Quiescent Supply Current	6.0	V _{IN} = V _{CC} or GND, I _{OUT} = 0 μA		2.0	20	40	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- For a power supply of 5 V ±10% the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5 V. Thus the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5 V and 4.5 V respectively. (The V_{IH} value at 5.5 V is 3.85 V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0 V values should be used.

MM74HC08

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0\text{ V}$, $T_A = 25^\circ\text{C}$, $C_L = 15\text{ pF}$, $t_r = t_f = 6\text{ ns}$)

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Unit
t_{PHL}	Maximum Propagation Delay, Output HIGH-to-LOW		12	20	ns
t_{PLH}	Maximum Propagation Delay, Output LOW-to-HIGH		7	15	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = 2.0\text{ V to }6.0\text{ V}$, $C_L = 50\text{ pF}$, $t_r = t_f = 6\text{ ns}$, (unless otherwise specified))

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = 25°C		T _A = −40°C to 125°C	Unit
				Typ	Guaranteed Limits		
t _{PHL}	Maximum Propagation Delay, Output HIGH-to-LOW	2.0		77	121	175	ns
		4.5		15	24	35	
		6.0		13	20	30	
t _{PLH}	Maximum Propagation Delay, Output LOW-to-HIGH	2.0		30	90	134	ns
		4.5		10	18	27	
		6.0		8	15	23	
t _{TLH} , t _{THL}	Maximum Output Rise and Fall Time	2.0		30	75	110	ns
		4.5		8	15	22	
		6.0		7	13	19	
C _{PD}	Power Dissipation Capacitance (Note 3)		(per gate)	38			pF
C _{IN}	Maximum Input Capacitance			4	10	10	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

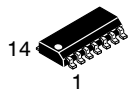
3. C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MM74HC08M	HC08A	SOIC-14 NB, Case 751A (Pb-Free and Halide Free)	55 Units / Tube
MM74HC08MX	HC08A	SOIC 14, Case 751EF (Pb-Free and Halide Free)	2500 Units / Tape & Reel
MM74HC08MTC	HC 08A	TSSOP-14 WB, Case 948G (Pb-Free and Halide Free)	96 Units / Tube
MM74HC08MTCX	HC 08A		2500 Units / Tape & Reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

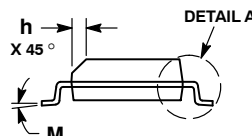
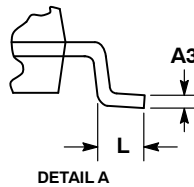
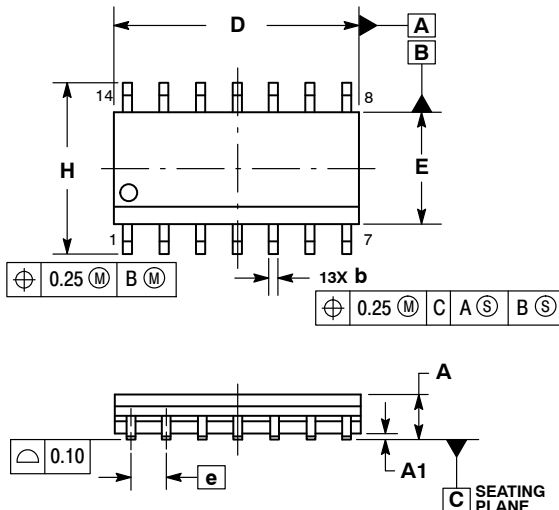
NOTE: All packages are lead free per JEDEC: J-STD-020B standard.



SCALE 1:1

SOIC-14 NB
CASE 751A-03
ISSUE L

DATE 03 FEB 2016

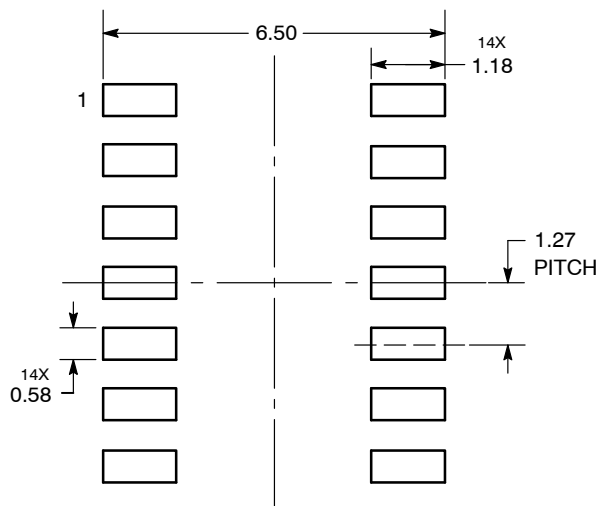


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

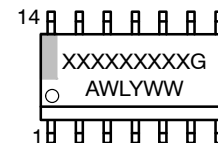
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



XXXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SOIC-14
CASE 751A-03
ISSUE L

DATE 03 FEB 2016

STYLE 1:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. NO CONNECTION
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. NO CONNECTION
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 2:
CANCELLED

STYLE 3:
PIN 1. NO CONNECTION
2. ANODE
3. ANODE
4. NO CONNECTION
5. ANODE
6. NO CONNECTION
7. ANODE
8. ANODE
9. ANODE
10. NO CONNECTION
11. ANODE
12. ANODE
13. NO CONNECTION
14. COMMON CATHODE

STYLE 4:
PIN 1. NO CONNECTION
2. CATHODE
3. CATHODE
4. NO CONNECTION
5. CATHODE
6. NO CONNECTION
7. CATHODE
8. CATHODE
9. CATHODE
10. NO CONNECTION
11. CATHODE
12. CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 5:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. NO CONNECTION
7. COMMON ANODE
8. COMMON CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 6:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. ANODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE

STYLE 7:
PIN 1. ANODE/CATHODE
2. COMMON ANODE
3. COMMON CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. ANODE/CATHODE
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. COMMON CATHODE
12. COMMON ANODE
13. ANODE/CATHODE
14. ANODE/CATHODE

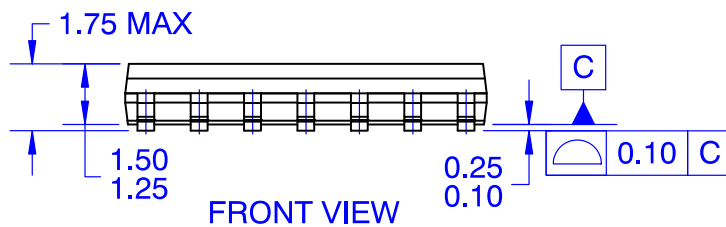
STYLE 8:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. ANODE/CATHODE
7. COMMON ANODE
8. COMMON ANODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. NO CONNECTION
12. ANODE/CATHODE
13. ANODE/CATHODE
14. COMMON CATHODE

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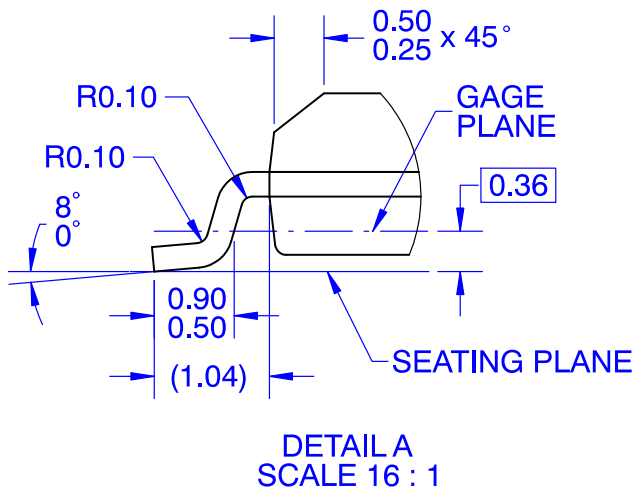
SOIC14
CASE 751EF
ISSUE O

DATE 30 SEP 2016



NOTES:

- A. CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C
- B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS
- D. LAND PATTERN STANDARD: SOIC127P600X145-14M
- E. CONFORMS TO ASME Y14.5M, 2009



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TSSOP-14 WB
CASE 948G
ISSUE C

DATE 17 FEB 2016

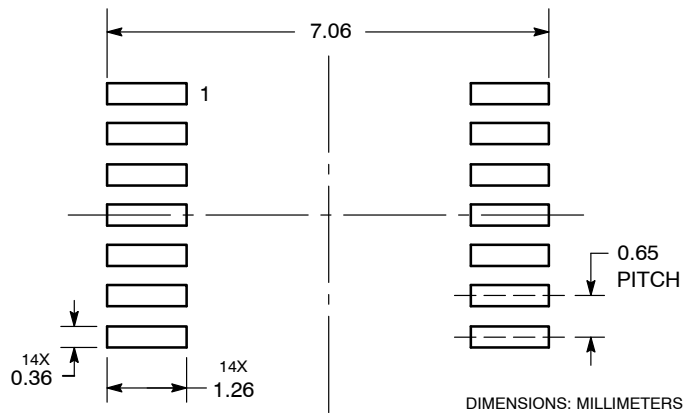
SCALE 2:1



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

**RECOMMENDED
SOLDERING FOOTPRINT***


*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**GENERIC
MARKING DIAGRAM***


A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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